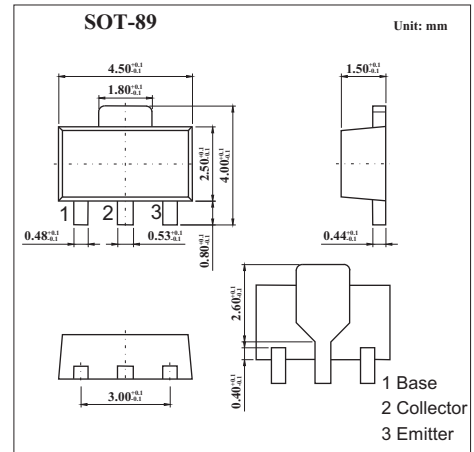


PNP Transistors

2SB1561-Q

Features

- Collector Current Capability $I_C = -2A$
- Collector Emitter Voltage $V_{CE0} = -60V$
- Low saturation Voltage typically
- $V_{CE(SAT)} = -0.15V$ at $I_C/I_B = -1A/-50mA$



Absolute Maximum Ratings $T_a = 25$

Parameter	Symbol	Rating	Unit
Collector - Base Voltage	V_{CB0}	-60	V
Collector - Emitter Voltage	V_{CE0}	-60	
Emitter - Base Voltage	V_{EB0}	-6	
Collector Current - Continuous	I_C	-0.5	A
	I_{CP}	-6	
Collector Power Dissipation	P_C	0.5	W
	P_{CM}	2	
Junction Temperature	T_J	150	
Storage Temperature range	T_{stg}	-55 to 150	

Electrical Characteristics $T_a = 25$

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector- base breakdown voltage	V_{CB0}	$I_C = -50 \mu A, I_E = 0$	-60			V
Collector- emitter breakdown voltage	V_{CE0}	$I_C = -1 mA, I_B = 0$	-60			
Emitter - base breakdown voltage	V_{EB0}	$I_E = -50 \mu A, I_C = 0$	-6			
Collector-base cut-off current	I_{CBO}	$V_{CB} = -50 V, I_E = 0$			-100	nA
Collector- emitter cut-off current	I_{CEO}	$V_{CB} = -48 V, I_E = 0$			-700	
Emitter cut-off current	I_{EBO}	$V_{EB} = -5V, I_C = 0$			-100	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -1A, I_B = -50mA$		-0.15	-0.35	V
Base - emitter saturation voltage	$V_{BE(sat)}$	$I_C = -1A, I_B = -50mA$			-1.2	
DC current gain	$h_{FE(1)}$	$V_{CE} = -2V, I_C = -0.5A$	120		270	
	$h_{FE(2)}$	$V_{CE} = -2V, I_C = -1.5A$	45			
Output capacitance	C_{ob}	$V_{CB} = -10V, I_E = 0A, f = 1MHz$		23		pF
Transition frequency	f_T	$V_{CE} = -2V, I_E = -0.5A, f = 100MHz$		200		MHz

Marking

Marking	BL/QN
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2SB1561-Q

Typical Characteristics

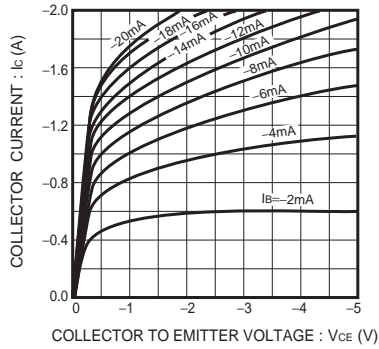


Fig.1 Grounded emitter output characteristics

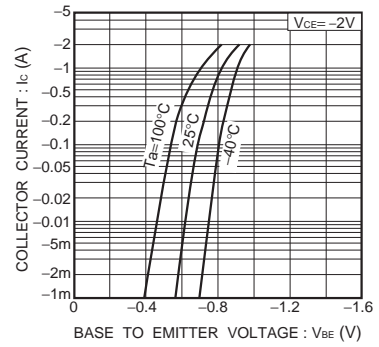


Fig.2 Grounded emitter propagation characteristics

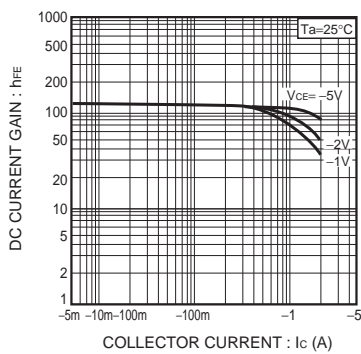


Fig.3 DC current gain vs. collector current (II)

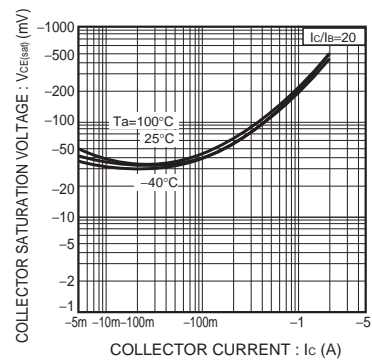


Fig.4 Collector-emitter saturation voltage vs. collector current (I)

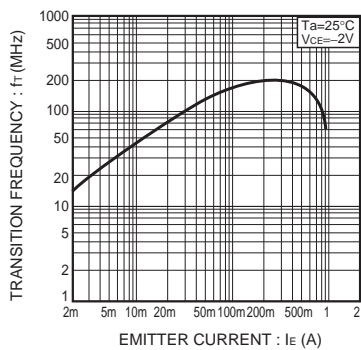


Fig.5 Gain bandwidth product vs. emitter current

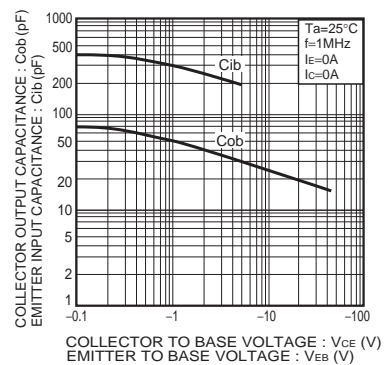


Fig.6 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

2SB1561-Q

■ Typical Characteristics

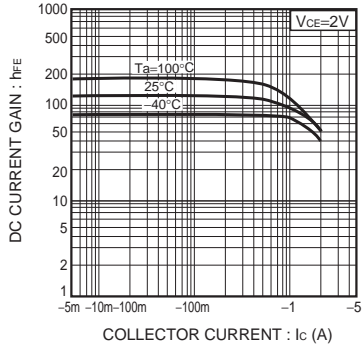


Fig.3 DC current gain vs. collector current (I)

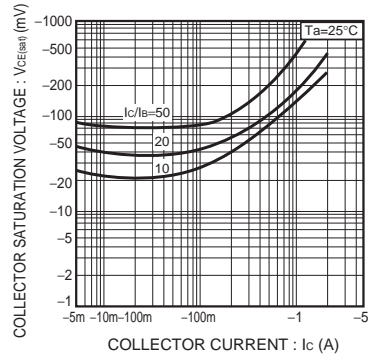


Fig.6 Collector-emitter saturation voltage vs. collector current (II)

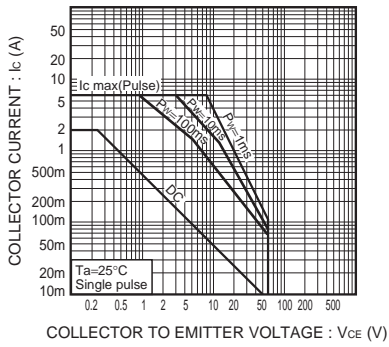


Fig.9 Safe operating area